NSN 5962-01-182-0553

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

794.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Case Outline Source And Designator:

D-2 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds delay

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0